Product data sheet

1. General description

Silicon Carbide Schottky diode in a DFN 8*8 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- · Highly stable switching performance
- High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- · Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	50		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _c ≤ 153 °C; Fig. 1; Fig. 2; Fig. 3	6			А	
T _j	junction temperature			175			°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 6 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.5	1.7	V
		I _F = 6 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.8	2.1	V
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 6 \text{ A}; dI_F/dt = 500 \text{ A/}\mu\text{s}; V_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 7$		-	9	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	[κ_I/_ Δ
2	n.c.	not connected	5	K — A 001aaa020
3	А	anode		
4	А	anode	<u> </u>	
5	К	mounting base; connected to cathode	1 2 3 4	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC06650T	DFN8*8	WNSC06650T6J	Tape	3000	DFN8X8N	25-Dec-2019

7. Marking

Table 4. Marking codes

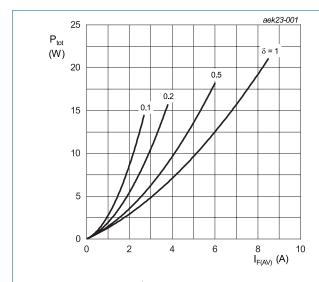
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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V_{RWM}	crest working reverse voltage		650	V
V_R	reverse voltage	DC	650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_c \le 153$ °C; Fig. 1; Fig. 2; Fig. 3	6	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 μs; T_c ≤ 153 °C; square-wave pulse	12	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	36	А
	forward current	t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse	310	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	6	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 1.140 \text{ V; } R_{\text{s}} = 0.1577 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

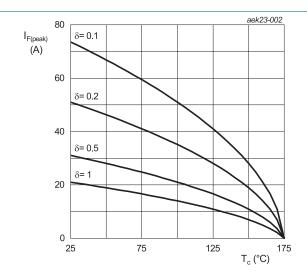


Fig. 2. Current derating as a function of case temperature

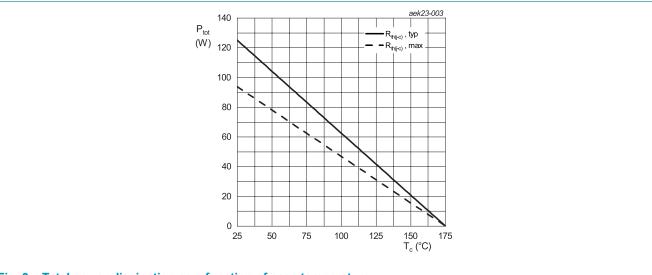
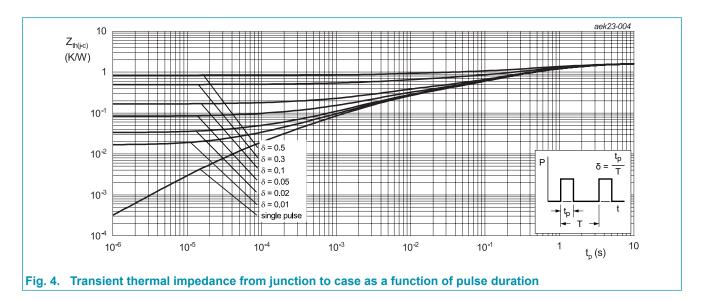


Fig. 3. Total power dissipation as a function of case temperature

9. Thermal characteristics

Table 6. Thermal characteristics

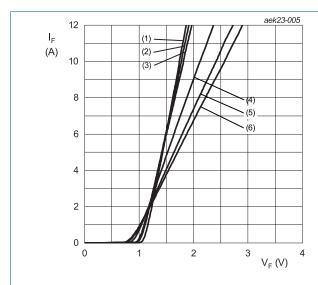
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-c)}	thermal resistance from junction to case	Fig. 4	-	1.2	1.6	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V_{F}	forward current	I _F = 6 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I _F = 6 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.8	2.1	V
		I _F = 6 A; T _j = 175 °C; <u>Fig. 5</u>		2	2.25	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>	-		40	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>	-		160	μA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 6 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	9	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	190	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	30	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	29	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 4.25 \text{ A}$; L = 5 mH; $T_{j(init)} = 25 \text{ °C}$	45	-	-	mJ



 $V_o = 1.140 \text{ V}; R_s = 0.1577 \Omega$

(1) $T_j = -55$ °C; typical values

(2) $T_j = 0$ °C; typical values (3) $T_j = 25$ °C; typical values

(4) T_i = 100 °C; typical values

(5) T_i = 150 °C; typical values (6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

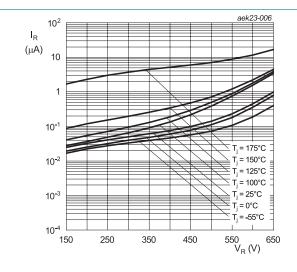
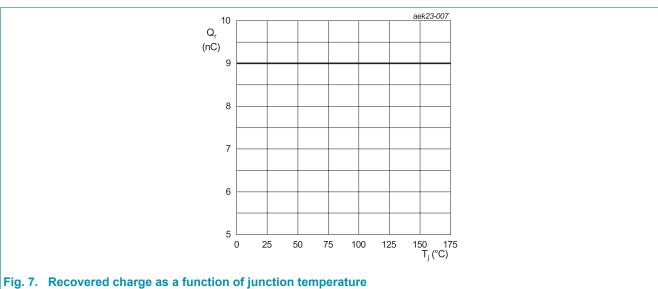
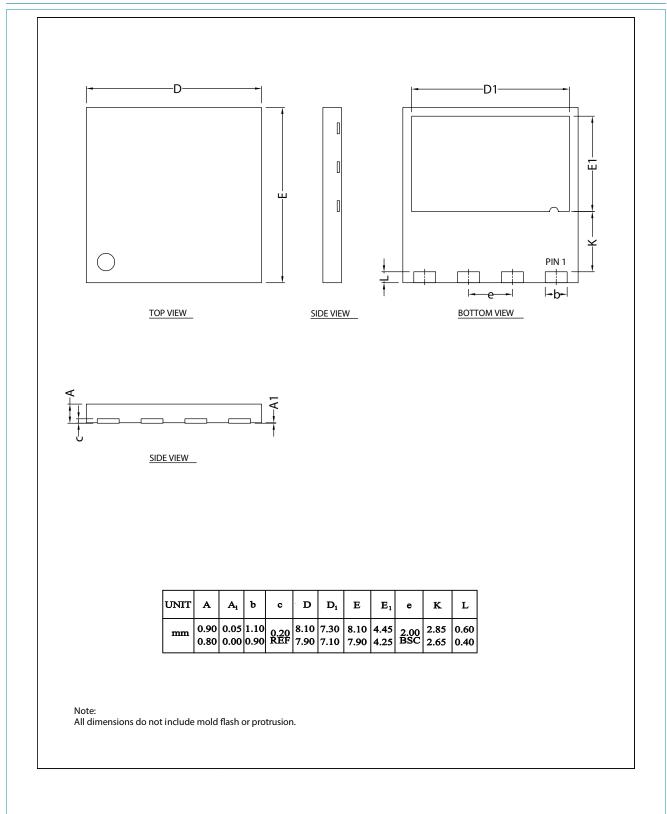


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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